

# DATA SHEET

查询"NP83P06PDG-E2-AY"供应商  
**NEC**

## MOS FIELD EFFECT TRANSISTOR **NP83P06PDG**

### SWITCHING P-CHANNEL POWER MOSFET

#### DESCRIPTION

The NP83P06PDG is P-channel MOS Field Effect Transistor designed for high current switching applications.

#### <R> ORDERING INFORMATION

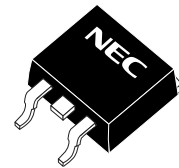
PART NUMBER	LEAD PLATING	PACKING	PACKAGE
NP83P06PDG-E1-AY <sup>Note</sup>	Pure Sn (Tin)	Tape 800 p/reel	TO-263 (MP-25ZP)
NP83P06PDG-E2-AY <sup>Note</sup>			

**Note** Pb-free (This product does not contain Pb in external electrode.)

#### FEATURES

- Super low on-state resistance  
 $R_{DS(on)1} = 8.8 \text{ m}\Omega \text{ MAX. (} V_{GS} = -10 \text{ V, } I_D = -41.5 \text{ A)}$   
 $R_{DS(on)2} = 12 \text{ m}\Omega \text{ MAX. (} V_{GS} = -4.5 \text{ V, } I_D = -41.5 \text{ A)}$
- High current rating:  $I_{D(DC)} = \mp 83 \text{ A}$

(TO-263)



#### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

Drain to Source Voltage (V <sub>GS</sub> = 0 V)	V <sub>DSS</sub>	-60	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	V <sub>GSS</sub>	±20	V
Drain Current (DC) (T <sub>C</sub> = 25°C)	I <sub>D(DC)</sub>	±83	A
Drain Current (pulse) <sup>Note1</sup>	I <sub>D(pulse)</sub>	±249	A
Total Power Dissipation (T <sub>C</sub> = 25°C)	P <sub>T1</sub>	150	W
Total Power Dissipation (T <sub>A</sub> = 25°C)	P <sub>T2</sub>	1.8	W
Channel Temperature	T <sub>ch</sub>	175	°C
Storage Temperature	T <sub>stg</sub>	-55 to +175	°C
Single Avalanche Current <sup>Note2</sup>	I <sub>AS</sub>	49	A
Single Avalanche Energy <sup>Note2</sup>	E <sub>AS</sub>	240	mJ

**Notes 1.** PW ≤ 10 μs, Duty Cycle ≤ 1%

**2.** Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = -30 V, R<sub>G</sub> = 25 Ω, V<sub>GS</sub> = -20 → 0 V

#### THERMAL RESISTANCE

Channel to Case Thermal Resistance	R <sub>th(ch-C)</sub>	1.0	°C/W
Channel to Ambient Thermal Resistance	R <sub>th(ch-A)</sub>	83.3	°C/W

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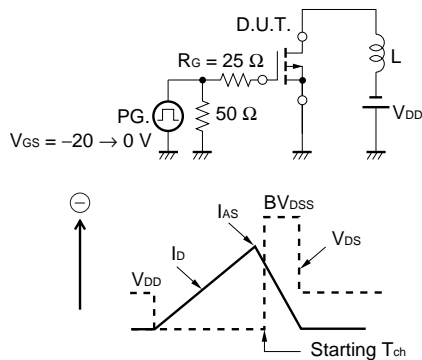
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**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)**

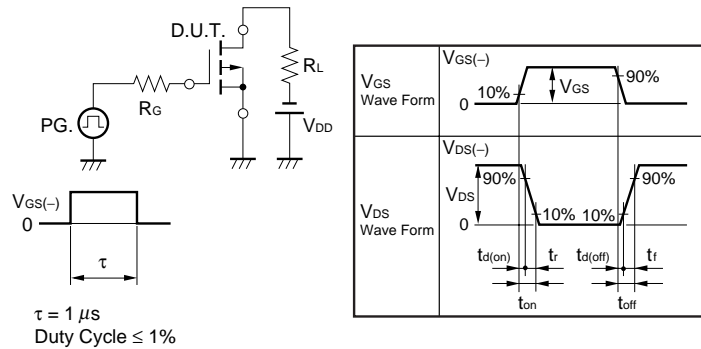
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = -60 V, V <sub>GS</sub> = 0 V			-10	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±100	nA
Gate to Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1 mA	-1.0	-1.6	-2.5	V
Forward Transfer Admittance <sup>Note</sup>	y <sub>fs</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -41.5 A	30	60		S
Drain to Source On-state Resistance <sup>Note</sup>	R <sub>DS(on)1</sub>	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -41.5 A		6.9	8.8	mΩ
	R <sub>DS(on)2</sub>	V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -41.5 A		8.0	12	mΩ
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -10 V,		10100		pF
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V,		1140		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1 MHz		660		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = -30 V, I <sub>D</sub> = -41.5 A,		36		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = -10 V,		20		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 0 Ω		230		ns
Fall Time	t <sub>f</sub>			200		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = -48 V,		190		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = -10 V,		20		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = -83 A		53		nC
Body Diode Forward Voltage <sup>Note</sup>	V <sub>F(S-D)</sub>	I <sub>F</sub> = -83 A, V <sub>GS</sub> = 0 V		0.94	1.5	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = -83 A, V <sub>GS</sub> = 0 V,		63		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = -100 A/μs		101		nC

**Note** Pulsed test PW ≤ 350 μs, Duty Cycle ≤ 2%

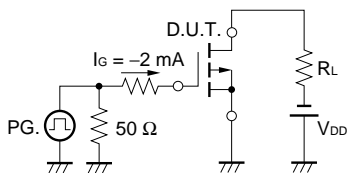
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



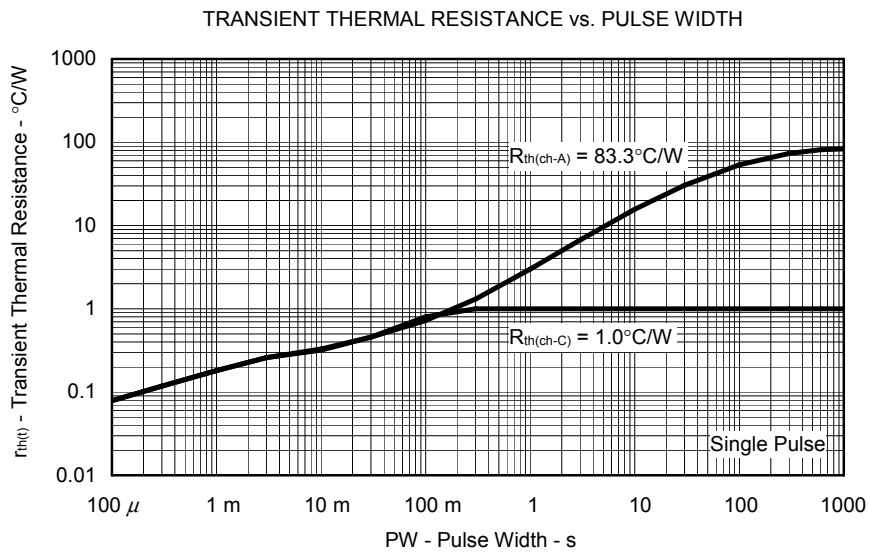
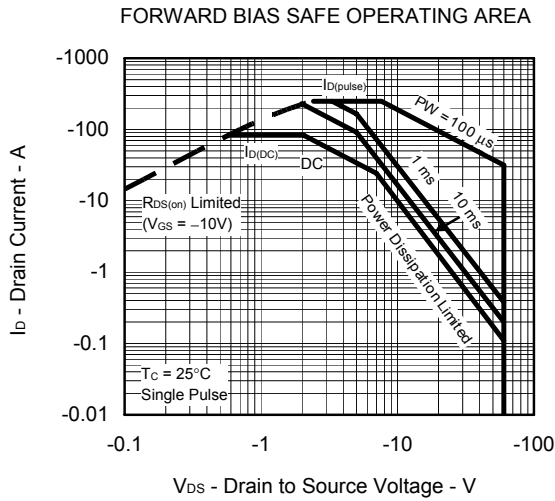
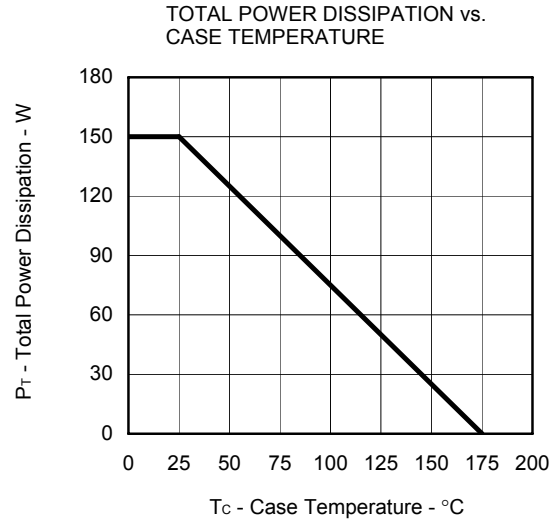
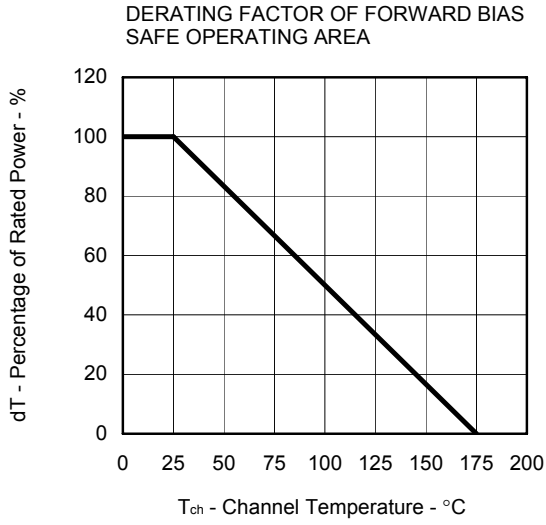
**TEST CIRCUIT 2 SWITCHING TIME**

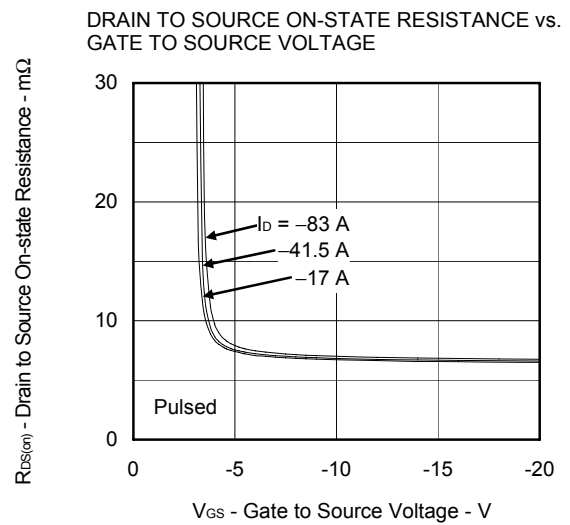
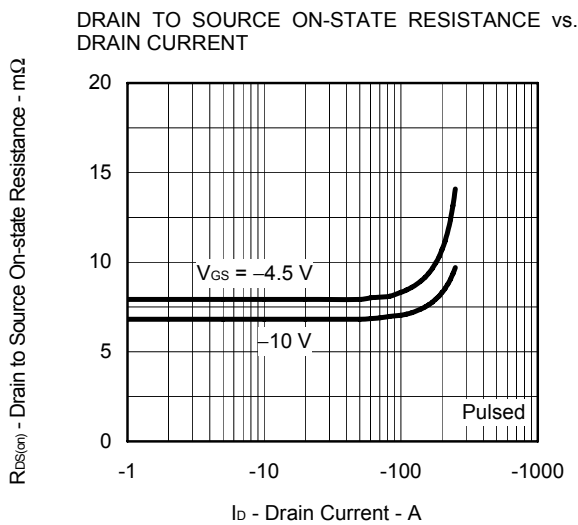
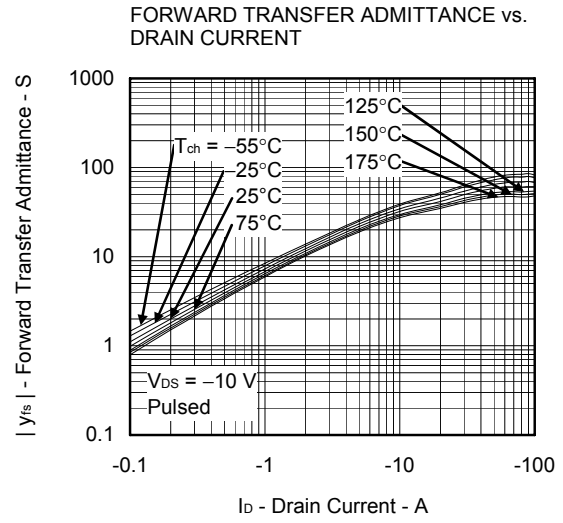
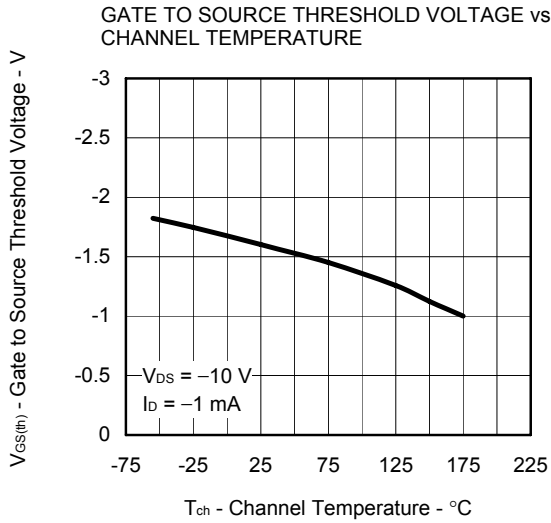
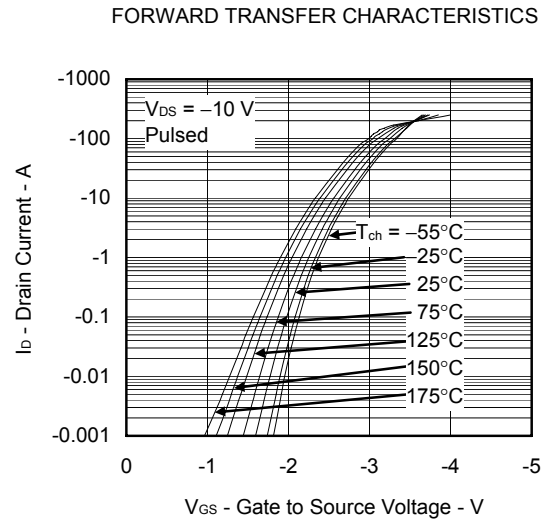
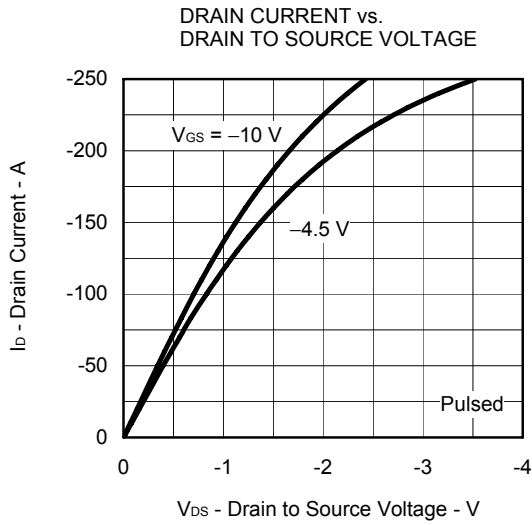


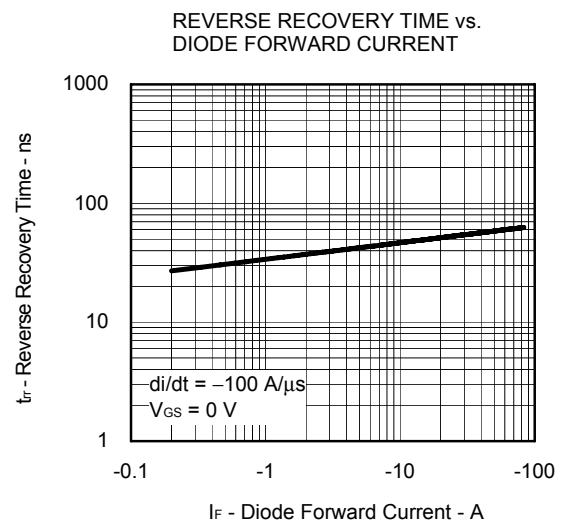
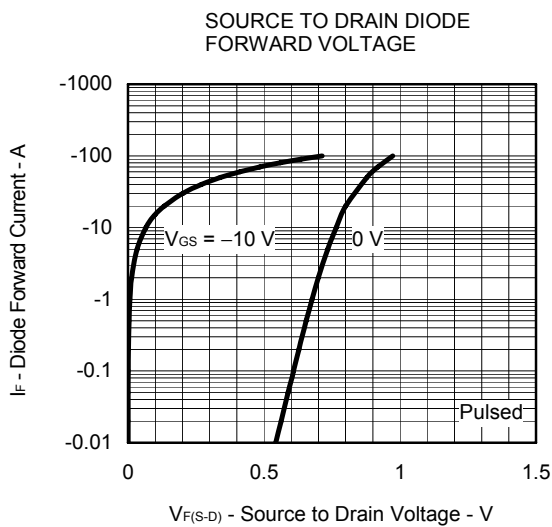
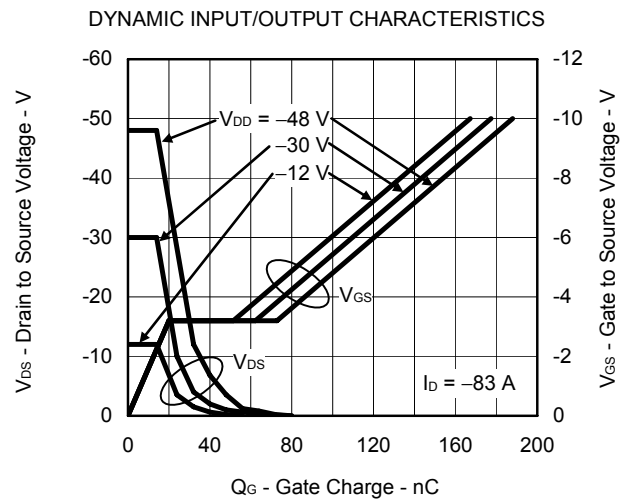
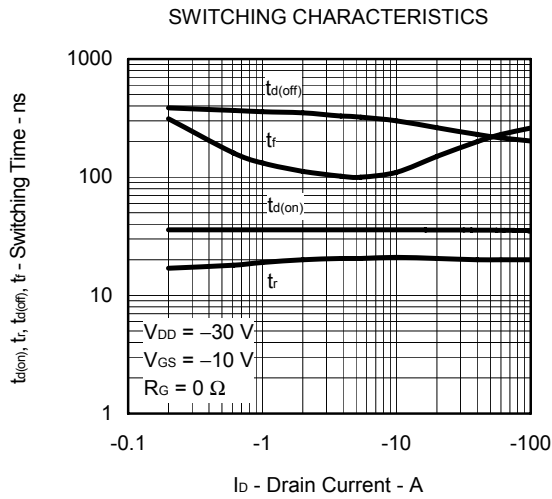
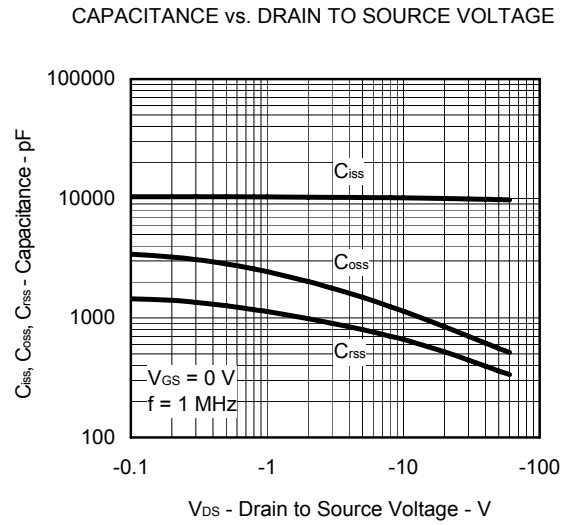
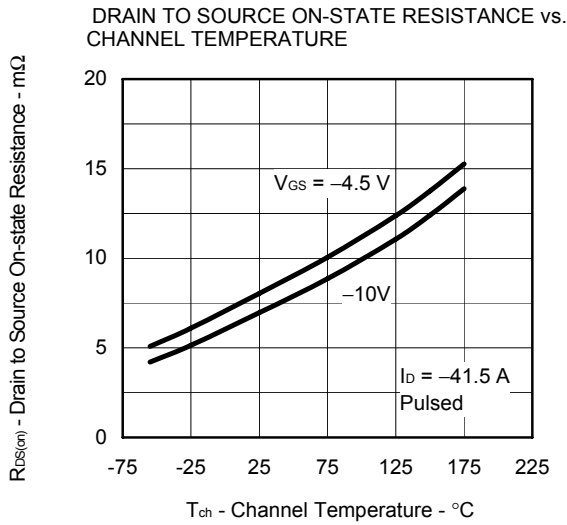
**TEST CIRCUIT 3 GATE CHARGE**



TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

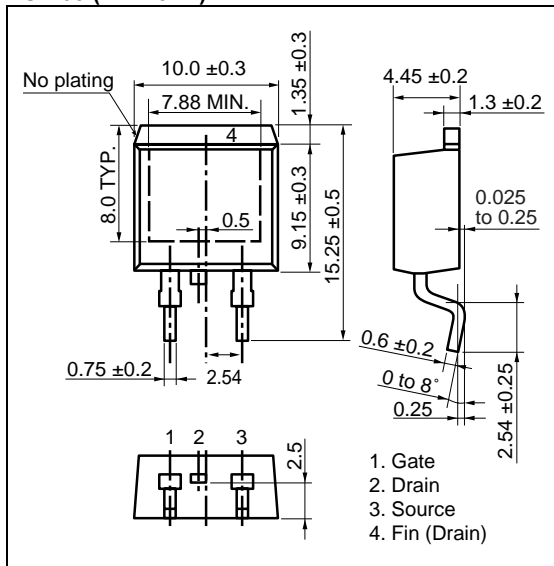




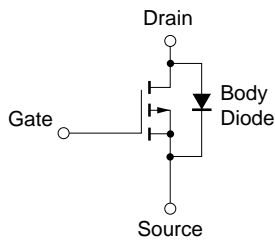


PACKAGE DRAWING (Unit: mm)

TO-263 (MP-25ZP)



EQUIVALENT CIRCUIT



**Remark** Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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